

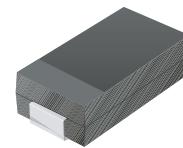
SMD Schottky Barrier Rectifier

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→

SS22-G THRU SS210-G

Reverse Voltage: 20 ~ 100 Volts

Forward Current: 2.0 Amp

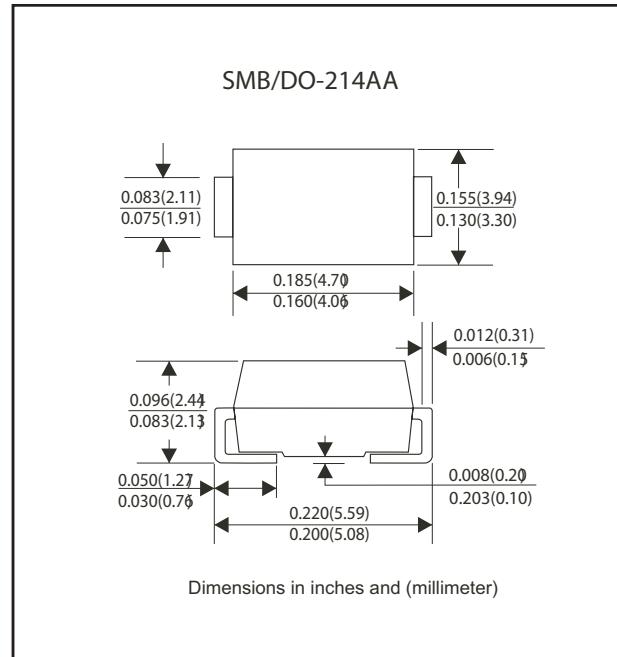


Features

- Ideal for surface mount applications
- Easy pick and place
- Plastic package has Underwriters lab. flammability classification 94V-0
- Built-in strain relief
- Low forward voltage drop

Mechanical Data

- Case: JEDEC DO-214AA molded plastic
- Terminal: Solderable per MIL-STD-750 method 2026
- Polarity: Color band denotes cathode end
- Mounting position: Any
- Weight: 0.093 gram



Maximum Rating and Electrical Characteristics

Parameter	Symbol	SS22-G	SS24-G	SS26-G	SS210-G	Unit
Max. Repetitive Peak Reverse Voltage	V _{RRM}	20	40	60	100	V
Max. DC Blocking Voltage	V _{DC}	20	40	60	100	V
Max. RMS Voltage	V _{RMS}	14	28	42	70	V
Peak Surge Forward Current 8.3ms single halfsine-wave superimposed on rateload (JEDEC method)	I _{FSM}			50		A
Max. Average Forward Current	I _o			2.0		A
Max. Instantaneous Forward Current at 2.0 A	V _F		0.50	0.70	0.85	V
Max. DC Reverse Current at Rated DC Blocking Voltage Ta=25°C	I _R		0.5			mA
			20	10		
Ta=100°C						
Max. Thermal Resistance (Note 1)	R _{θJA} R _{θJL}		75 17			°C/W
Operating Junction temperature	T _j		-50 to +125			°C
Storage Temperature	T _{STG}		-65 to +150			°C

Note 1: Thermal resistance from junction to ambient and junction to tolead P.C.B. Mounted on 0.2 x 0.2 copper pad areas

"-G" suffix designates RoHS compliant Version

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Rating and Characteristic Curevs (SS22-G Thru SS2100-G)

Fig. 1 - Reverse Characteristics

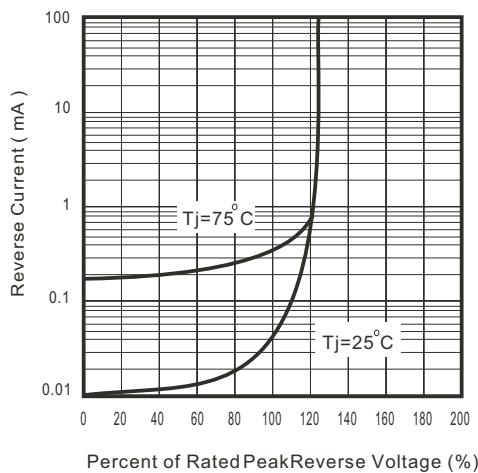


Fig.2 - Forward Characteristics

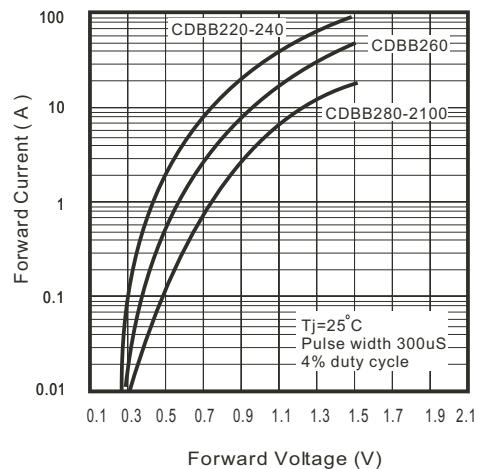


Fig. 3 - Junction Capacitance

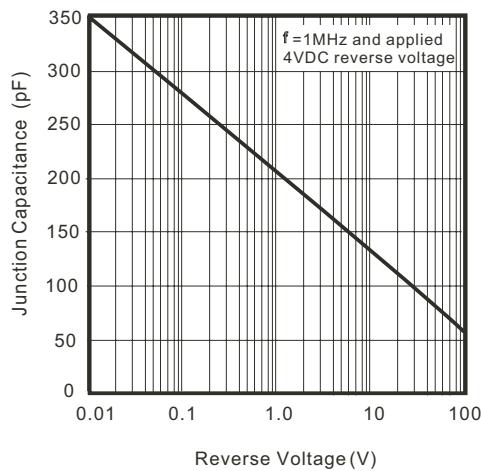


Fig. 4 - Current Derating Curve

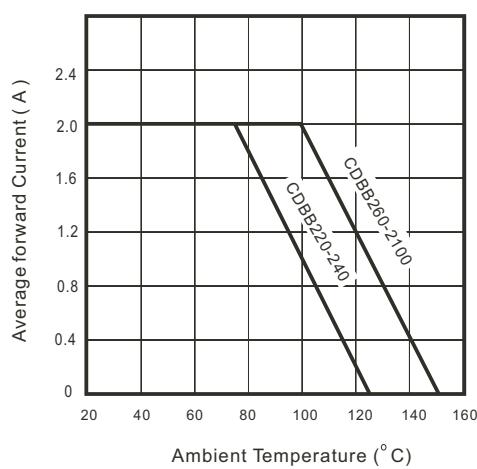


Fig. 5 - Non Repetitive Forward Surge Current

